NSN 5961-01-003-7345

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Inclosure Material:

Metal all transistor

Overall Length:

0.170 inches all transistor and 0.210 inches all transistor

Terminal Length:

0.500 inches all transistor and 0.750 inches all transistor

Overall Diameter:

0.178 inches all transistor and 0.230 inches all transistor

Function For Which Designed:

Chopper

Internal Configuration:

Field effect all transistor

Channel Polarity And Control Type (non-core):

N-channel junction type all transistor

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-18 all transistor

Electrode Internally-electrically Connected To Case:

Gate all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal all transistor

Terminal Circle Diameter:

0.100 inches all transistor

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

-40.0 gate to source voltage all transistor and 40.0 drain to source voltage all transistor and 40.0 drain to gate voltage all transistor

Current Rating Per Characteristic:

50.00 milliamperes source cutoff current minor all transistor

Power Rating Per Characteristic:

1.8 watts small-signal input power, common-collector preset all transistor

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction all transistor

Terminal Type And Quantity:

3 uninsulated wire lead all transistor

Shelf Life:

N/a

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In	18	<i>(</i>)+	МЛО	201	ure:

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Demilitarization:

No

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